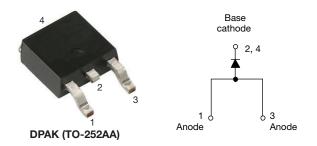
Vishay Semiconductors

# Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



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PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	8 A						
V <sub>R</sub>	200 V, 400 V, 600 V						
V <sub>F</sub> at I <sub>F</sub>	1.2 V						
I <sub>FSM</sub>	150 A						
t <sub>rr</sub>	55 ns						
T <sub>J</sub> max.	150 °C						
Snap factor	0.5						
Package	DPAK (TO-252AA)						
Circuit configuration	Single						

## FEATURES

- · Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### APPLICATIONS

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

### DESCRIPTION

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Sinusoidal waveform	8	A						
V <sub>RRM</sub>		200 to 600	V						
I <sub>FSM</sub>		150	A						
V <sub>F</sub>	8 A, T <sub>J</sub> = 25 °C	1.2	V						
t <sub>rr</sub>	1 A, 100 A/µs	55	ns						
TJ	Range	-40 to +150	°C						

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-8EWF02S-M3	200	300							
VS-8EWF04S-M3	400	500	3						
VS-8EWF06S-M3	600	700							

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	$T_{C}$ = 96 °C, 180° conduction half sine wave	8						
Maximum peak one cycle	I <sub>FSM</sub>	10 ms sine pulse, rated $V_{RRM}$ applied	125	А					
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	150						
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	78	A <sup>2</sup> s					
Maximum 14t for fusing		10 ms sine pulse, no voltage reapplied 110		A-S					
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s					

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum forward voltage drop	V <sub>FM</sub>	8 A, T <sub>J</sub> = 25 °C		1.2	V			
Forward slope resistance	r <sub>t</sub>	T.ı = 150 °C	16	mΩ				
Threshold voltage	V <sub>F(TO)</sub>	1j = 150 C	1.13	V				
		$T_J = 25 \text{ °C}$		0.1	mA			
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	3	ША			

RECOVERY CHARACTERISTICS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Reverse recovery time	t <sub>rr</sub>	l <sub>F</sub> at 1 A <sub>pk</sub> 100 A/µs T <sub>J</sub> = 25 °C	55	ns				
		I <sub>F</sub> at 8 A <sub>pk</sub>	200					
Reverse recovery current	I <sub>rr</sub>	25 A/µs	2.6	А				
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	0.25	μC				
Snap factor	S		0.5					

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C				
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5	°C/W				
Typical thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> <sup>(1)</sup>		50	0/00				
Approximate weight			1	g				
Approximate weight			0.03	oz.				
			8EWF02S					
Marking device		Case style DPAK (TO-252AA)	8EWF04S					
			8EWF06S					

Note

(1) When mounted on 1" square (650 mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



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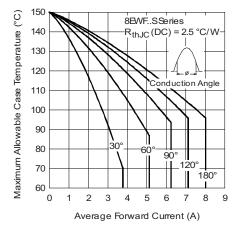


Fig. 1 - Current Rating Characteristics

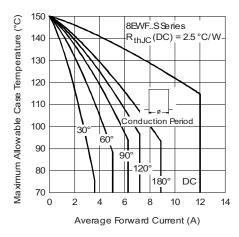


Fig. 2 - Current Rating Characteristics

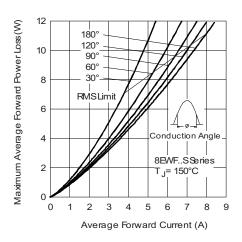


Fig. 3 - Forward Power Loss Characteristics

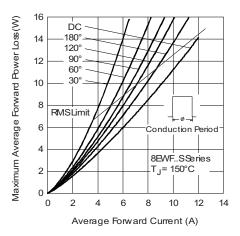


Fig. 4 - Forward Power Loss Characteristics

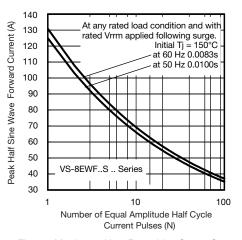


Fig. 5 - Maximum Non-Repetitive Surge Current

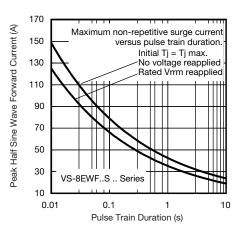


Fig. 6 - Maximum Non-Repetitive Surge Current

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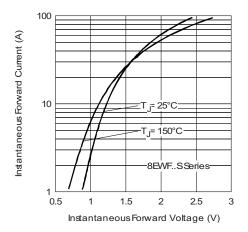


Fig. 7 - Forward Voltage Drop Characteristics

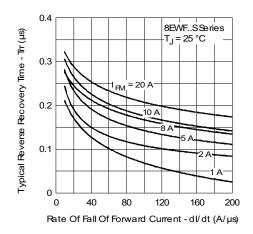


Fig. 8 - Recovery Time Characteristics,  $T_{\rm J}$  = 25  $^{\circ}{\rm C}$ 

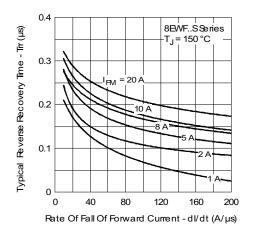


Fig. 9 - Recovery Time Characteristics,  $T_J = 150 \ ^{\circ}C$ 

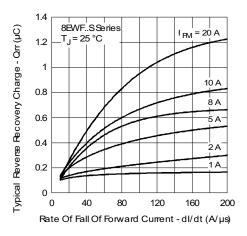


Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C

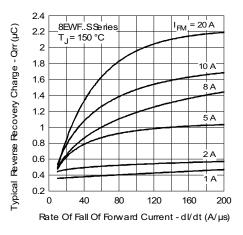


Fig. 11 - Recovery Charge Characteristics,  $T_J = 150 \ ^\circ C$ 

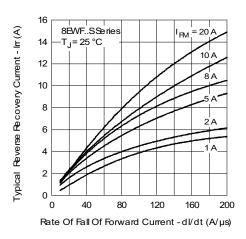


Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

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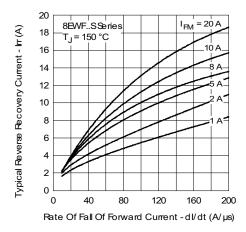


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

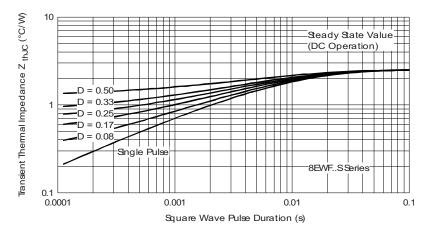


Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics

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## **ORDERING INFORMATION TABLE**

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Device code	VS-	8	Е	w	F	06	S	TR	-M3	
	1	2	3	4	5	6	7	8	9	
	<ol> <li>Vishay Semiconductors product</li> <li>Current rating (8 = 8 A)</li> </ol>									
	3 - Circuit configuration:									
	4 -	Pac	E = single diode Package:							
	5 -	Тур	D-PAK e of silic	con:						
	6			t recove le x 100	-		02 = 20 04 = 40			
	7 -		S = surface mountable $06 = 600 V$							
	8 -			e and ree be and r		nt orient	ed)			
			<ul> <li>TRR = tape and reel (right oriented)</li> <li>TRL = tape and reel (left oriented)</li> </ul>							
	9 -	Env	rironmer	ntal digit	:					

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-8EWF02S-M3	75	3000	Antistatic plastic tubes							
VS-8EWF02STR-M3	2000	2000	13" diameter reel							
VS-8EWF02STRL-M3	3000	3000	13" diameter reel							
VS-8EWF02STRR-M3	3000	3000	13" diameter reel							
VS-8EWF04S-M3	75	3000	Antistatic plastic tubes							
VS-8EWF04STR-M3	2000	2000	13" diameter reel							
VS-8EWF04STRL-M3	3000	3000	13" diameter reel							
VS-8EWF04STRR-M3	3000	3000	13" diameter reel							
VS-8EWF06S-M3	75	3000	Antistatic plastic tubes							
VS-8EWF06STR-M3	2000	2000	13" diameter reel							
VS-8EWF06STRL-M3	3000	3000	13" diameter reel							
VS-8EWF06STRR-M3	3000	3000	13" diameter reel							

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95627						
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95551						

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D-PAK (TO-252AA) "M"

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA



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Revision: 01-Jan-2025

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